



DESCRIPTION

The SSF2816E uses advanced trench technology to provide excellent $R_{\text{DS}(\text{ON})}$, low gate charge and operation with gate voltages as low as 2.5V.

GENERAL FEATURES

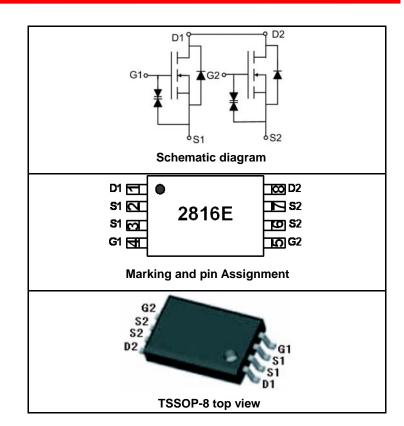
• $V_{DS} = 20V,I_D = 7A$ $R_{DS(ON)} < 30m\Omega @ V_{GS}=2.5V$ $R_{DS(ON)} < 26m\Omega @ V_{GS}=3.1V$ $R_{DS(ON)} < 23m\Omega @ V_{GS}=4V$ $R_{DS(ON)} < 22m\Omega @ V_{GS}=4.5V$

ESD Rating: 2500V HBM

- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- Battery protection
- Load switch
- Power management



PACKAGE MARKING AND ORDERING INFORMATION

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|----------|----------------|-----------|------------|------------|
| 2816E | SSF2816E | TSSOP-8 | Ø330mm | 12mm | 3000 units |

ABSOLUTE MAXIMUM RATINGS(TA=25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|-----------------|------------|------|
| Drain-Source Voltage | Vds | 20 | V |
| Gate-Source Voltage | Vgs | ±12 | V |
| Drain Current Continuous@ Current Ruland (Note 1) | Ι _D | 7 | A |
| Drain Current-Continuous@ Current-Pulsed (Note 1) | I _{DM} | 25 | A |
| Maximum Power Dissipation | PD | 1.5 | W |
| Operating Junction and Storage Temperature Range | T_{J},T_{STG} | -55 To 150 | °C |

THERMAL CHARACTERISTICS

| Thermal Resistance, Junction-to-Ambient (Note 2)R _{0JA} 83°C/W |
|---|
|---|

ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|--------------------------------|-------------------|---|-----|-----|-----|------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 20 | | | V |

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SSF2816E

| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =20V,V _{GS} =0V | | | 1 | μA |
|------------------------------------|---------------------|---|-----|------|------|----|
| Coto Rodul polyago Current | 1 | V_{GS} =±4.5V, V_{DS} =0V | | | ±200 | nA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±10V,V _{DS} =0V | | | ±10 | uA |
| ON CHARACTERISTICS (Note 3) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} ,I _D =250µA | 0.6 | 0.75 | 1.2 | V |
| | _ | V _{GS} =4.5V, I _D =6.5A | | 16.5 | 22 | mΩ |
| Drain-Source On-State Resistance | | V _{GS} =4V, I _D =6A | | 17 | 23 | mΩ |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =3.1V, I _D =5.5A | | 19 | 26 | mΩ |
| | | V _{GS} =2.5V, I _D =5.5A | | 22 | 30 | mΩ |
| Forward Transconductance | g fs | V _{DS} =10V,I _D =6.5A | | 6.6 | | S |
| DYNAMIC CHARACTERISTICS (Note4) | | | | | | |
| Input Capacitance | Clss | | | 600 | | PF |
| Output Capacitance | C _{oss} | V _{DS} =8V,V _{GS} =0V, F=1.0MHz | | 330 | | PF |
| Reverse Transfer Capacitance | C _{rss} | | | 140 | | PF |
| SWITCHING CHARACTERISTICS (Note 4) | | | | | | |
| Turn-on Delay Time | t _{d(on)} | | | 10 | 20 | nS |
| Turn-on Rise Time | tr | V _{DD} =10V,I _D =1A | | 11 | 25 | nS |
| Turn-Off Delay Time | $t_{\text{d(off)}}$ | V_{GS} =4.5V, R_{GEN} =6 Ω | | 35 | 70 | nS |
| Turn-Off Fall Time | t _f | | | 30 | 60 | nS |
| Total Gate Charge | Qg | | | 10 | 15 | nC |
| Gate-Source Charge | Q _{gs} | V _{DS} =10V,I _D =7A, V _{GS} =4.5V | | 2.3 | | nC |
| Gate-Drain Charge | Q _{gd} | | | 3 | | nC |
| DRAIN-SOURCE DIODE CHARACTERISTICS | | • | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =1.5A | | 0.84 | 1.2 | V |

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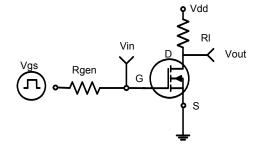
NOTES:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec. **3.** Pulse Test: Pulse Width $\le 300 \mu$ s, Duty Cycle $\le 2\%$. **4.** Guaranteed by design, not subject to production testing.



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



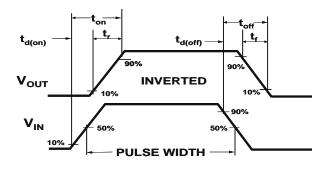


Figure 1:Switching Test Circuit

Figure 2:Switching Waveforms

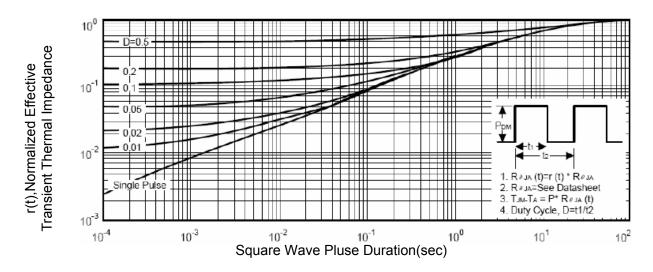
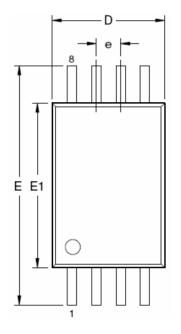


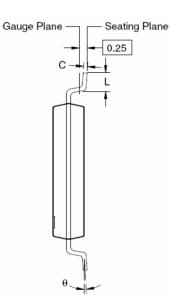
Figure 3 Normalized Maximum Transient Thermal Impedance

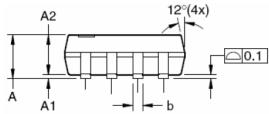
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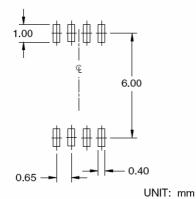
TSSOP-8 PACKAGE INFORMATION







RECOMMENDED LAND PATTERN



Dimensions in millimeters

| Symbols | Min. | Nom. | Max. | |
|---------|------------|------|------------|--|
| Α | _ | _ | 1.20 | |
| A1 | 0.05 | — | 0.15 | |
| A2 | 0.80 | 1.00 | 1.05 | |
| b | 0.19 | — | 0.30 | |
| С | 0.09 | _ | 0.20 | |
| D | 2.90 | 3.00 | 3.10 | |
| Е | 6.40 BSC | | | |
| E1 | 4.30 | 4.40 | 4.50 | |
| е | 0.65 BSC | | | |
| L | 0.45 | 0.60 | 0.75 | |
| θ | 0 ° | _ | 8 ° | |

Dimensions in inches

| Symbols | Min. | Nom. | Max. | | |
|---------|-----------|-------|-------|--|--|
| A | — | — | 0.047 | | |
| A1 | 0.002 | — | 0.006 | | |
| A2 | 0.031 | 0.039 | 0.041 | | |
| b | 0.007 | — | 0.012 | | |
| С | 0.004 | _ | 0.008 | | |
| D | 0.114 | 0.118 | 0.122 | | |
| E | 0.252 BSC | | | | |
| E1 | 0.169 | 0.173 | 0.177 | | |
| е | 0.026 BSC | | | | |
| L | 0.018 | 0.024 | 0.030 | | |
| θ | 0° | — | 8° | | |

NOTES:

Dimensions are inclusive of plating
Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 6 mils.

Dimension L is measured in gauge plane.
Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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